Double Exchange I: A Simple Introduction

Detian Yang 04/10/2020

Background: Ferromagnetic compounds of manganese with perovskite structure



1. Standard ceramic technique

2. $(La_{1-x}^{3+}Me_x^{2+})(Mn_{1-x}^{3+}Mn_x^{4+})O_3$; *Me*: large divalent ion like Ca^{2+} , Sr^{2+} , Ba^{2+} , Cd^{2+} , Pb^{2+}

3, x = 0, **1**: Semiconductor; 0.2 < x < 0.4: ferromagnetism and good conductivity

4, Correlation between magnetism and conductivity

G.H.Jonker and J.H. Van Santen, Physica 16, 337 (1950) G.H.Jonker and J.H. Van Santen, Physica 16, 599 (1950) G.H.Jonker, Physica 22, 707 (1956)

Double Exchange Mechanism: Indirect exchange via conduction electrons



 $(La_{1-x}^{3+}Sr_x^{2+})(Mn_{1-x}^{3+}Mn_x^{4+})O_3$

 Only Mn ions with incomplete d band
 Both Magnetism and conductivity from Mn ions: their interactions with each other and the crystal field

Double Exchange Mechanism: Indirect exchange via conduction electrons

Assumptions:

(1) Like free ions, all unpaired spins of incomplete 3d electrons pointing to the same direction;

(2) Exchange between d shells of adjacent atoms is antiferromagnetic and much smaller than double exchange

(3) The spin of an incomplete d shell is strongly coupled to the spin of conduction electrons (b << J)

(4) Conduction electrons do not change their spin orientation when Moving; accordingly they can hop from one ion to the next only if the two ionic spins are not antiparallel

(5) \vec{s} is parallel to \vec{S}_1 when in atom 1, while it is parallel to \vec{S}_2 when ln atom 2.

C. Zener, Phys.Rev. 82, 403 (1951) P. W. Anderson and H. Hasegawa, Phys. Rev. 100, 675 (1955)



$$\Delta H = \begin{bmatrix} -JS & b \\ b & -JS \end{bmatrix}$$

where, *J* is the exchange integral between \vec{s} and \vec{S}_i , i = 1, 2; transfer integral $b = \langle \varphi(r - R_2) | \Delta H | \varphi(r - R_1) \rangle$ $\approx 0.5 - 1 \, eV$

Double Exchange Mechanism: Indirect exchange via conduction electrons

$$\Delta H: \begin{array}{c} \varphi(r-R_1) & \varphi(r-R_2) \\ \varphi(r-R_1) & \begin{bmatrix} -JS & b \\ b & -JS \end{bmatrix} \\ \psi(r-R_2) & \begin{bmatrix} -JS & b \\ b & -JS \end{bmatrix} \end{array}$$

Eigenvalues:Eigenvectors:
$$\Delta E = -JS \pm b$$
 $\varphi_{\pm} = \frac{1}{\sqrt{2}} [\varphi(r - R_1) \pm \varphi(r - R_2)]$

If $kT_C < b$, $\Delta E = -JS - b$, ferromagnetic !

When the hopping is allowed, the ground state energy is lowered (since the conduction electrons are able to participate in the binding)

Double Exchange Mechanism: Conductivity

Hopping rate and average drift velocity of the conduction electron are :

$$v = \frac{2b}{h} \quad (1)$$

$$V = av \quad (2)$$
Since the diffusion coefficient *D* satisfies
$$\vec{J} = -D\nabla(xn) \quad (3)$$
Diffusion electric current $J = -(drift \ current) = -\frac{ex}{a^3}V \quad (4)$

$$\nabla(xn) = \frac{exn}{a} \quad (5)$$
Hence, $D = \frac{ex}{\frac{ex}{2}N} = aV \quad (6)$
Here *n* is the density of Mn; *x* is the fraction of Mn ions which have 4+ charge; *a* is lattice constant
Conductivity $\sigma = xne\mu \quad (7)$, where μ is the electron mobility
Also, Einstein relation $D = \frac{\mu kT}{e} \quad (8)$
Combing (1), (2), (6), (7) and (8), we have

$$\sigma = \frac{2be^2x}{hakT} \quad (9)$$
If $b \approx kT_C \quad (10)$

$$C. Zener, Phys.Rev. 82, 403 (1951)$$

agreeing well with the experimental data in the doping range 0.2 < x < 0.4